Inverse Spin-Valve-Type Magnetoresistance in Spin Engineered Multilayered Structures

J. M. George, L. G. Pereira, A. Barthélémy, F. Petroff, L. Steren, J. L. Duvail, and A. Fert
Laboratoire de Physique des Solides, Bâtiment 510, Université Paris-Sud, 91405 Orsay Cédex, France

R. Loloee, P. Holody, and P. A. Schroeder
Department of Physics and Astronomy and Center for Fundamental Materials Research, Michigan State University, East Lansing, Michigan 48824
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The resistivity of magnetic multilayers is generally smaller when the magnetizations of successive layers are parallel, which is the so-called giant magnetoresistance or spin-valve effect. We have been able to reverse this effect and to obtain a smaller resistivity for an antiparallel arrangement by intercalating thin Cr layers within half of the Fe layers in Fe/Cu multilayers. This inverse spin-valve effect is due to the inverse spin asymmetries of the electron scattering in successive Fe layers with and without Cr. This is a confirmation of the fundamental mechanism of the giant magnetoresistance.

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Giant magnetoresistance (GMR) effects [1,2] have now been observed in many magnetic multilayered structures. The resistivity is larger in the antiferromagnetic configuration, that is, when the magnetizations of successive magnetic layers are antiparallel. These magnetoresistance (MR) effects are currently ascribed to the conduction in parallel by the two spin directions and to the spin dependence of the electron scattering in the magnetic layers or at their interfaces [1,3,4].

The schematic of Fig. 1 illustrates the mechanism in the simple limit where the electron mean free path is much larger than the layer thicknesses. For simplicity the figure is drawn with only scattering at the interfaces (but there is also scattering within the layers). The schematic is for the case of minority spin (spin \( \downarrow \)) electrons more strongly scattered than the majority spin (spin \( \uparrow \)) electron, i.e., \( \alpha = \rho \downarrow /\rho \uparrow > 1 \) in the conventional notation [5]. When, as represented on the right, the magnetization of all the magnetic layers is parallel (high field ferromagnetic configuration), the conduction electrons with spin + (i.e., \( s_z = + \frac{1}{2} \)) are weakly scattered in all the layers, and form a low resistivity channel. The shunting of the current by this channel produces a low resistivity in the ferromagnetic (F) configuration. This is the normal spin-valve effect. If the two current picture is correct, it should be possible to reverse this MR effect by alternating magnetic layers \( M_1 \) and \( M_2 \) with \( a_1 < 1 \) and \( a_2 > 1 \), respectively, as illustrated by Fig. 1(b). In the antiferromagnetic (AF) configuration represented at the right of Fig. 1(b), the spins + are weakly scattered minority electrons in layer \( M_1 \) (since \( a_1 < 1 \)) and again weakly scattered minority electrons in the antiparallel layer \( M_2 \) (since \( a_2 > 1 \)). The shunting effect by this channel makes the resistivity smaller in the AF configuration, in contrast with the normal situation where the shunting effect occurs in the F configuration. A reversed MR is therefore expected in the situation of Fig. 1(b), with \( a_1 < 1 \) and \( a_2 > 1 \). Combinations of scatterings with \( a \) smaller and larger than 1 have already been used to

FIG. 1. Schematic picture of spin-valve effects in magnetic/nonmagnetic multilayers. Arrows indicate the majority spin direction in the magnetic layers for antiferromagnetic (AF, left) and ferromagnetic (F, right) arrangements. The electron trajectories between two scatterings are represented by straight lines and the scatterings by abrupt changes in direction. The spins + and − are for electron spins \( s_z = + \frac{1}{2} \) and \( s_z = - \frac{1}{2} \), respectively. (a) Normal MR: The spin asymmetry coefficient is the same for all the magnetic layers and is supposed to be larger than 1 for the figure. In the F configuration (right), the spin + electrons (\( s_z = + \frac{1}{2} \)) are weakly scattered by all the magnetic layers and the shunting of the current by this low resistivity channel makes the resistivity low in the F state, i.e., \( \rho_{AF} = \rho \downarrow /\rho \uparrow < \rho_{AF} = (\rho \downarrow + \rho \uparrow) / 4 \). (b) Reversed MR: The spin asymmetry coefficient is supposed to be smaller than 1 in the magnetic layer \( M_1 \) and larger than 1 in \( M_2 \). In the AF configuration (left), the spin + are weakly scattered minority spins in layer \( M_1 \) (since \( a_1 < 1 \)) and also weakly scattered majority spins in layer \( M_2 \) (since \( a_2 > 1 \)). The shunting of the current by the spin + channel now occurs in the AF configuration, i.e., \( \rho_{AF} < \rho_F \) (inverse MR).
modify the GMR [6], but to our knowledge, never to reverse it (that is, with \(a_1 < 1\) and \(a_2 > 1\) in successive layers, as described above).

We have performed MR measurements at room temperature with an usual four point technique on \((M_1/Cu/M_2/Cu) \times 5\) multilayers grown by dc magnetron sputtering. The structure of the multilayers is shown in Fig. 2:

(i) The magnetic layer \(M_2\) is a Fe layer. From electronic structure arguments [7,8], its asymmetry coefficient \(a_2\) is expected to be larger than 1.

(ii) The magnetic layer \(M_1\) is composed of 24 \(\AA\) of Fe in the center of which we have inserted 4 \(\AA\) of Cr. This thickness of Cr has been chosen to produce a ferromagnetic coupling between the two parts of the Fe layer [9] and to ensure that \(M_1\) behaves as a unique magnetic layer (we will, however, see that the ferromagnetic alignment is not perfect). Chromium has been chosen because the scattering by the Fe/Cr interfaces is known to be strongly spin dependent [7], with probably \(a < 1\) (by analogy with the case of Cr impurities in Fe [5] and also from other electronic structure arguments [8]). Of course, the scattering with \(a < 1\) by the Fe/Cr interfaces is not the only one in layer \(M_1\) and competes with scattering with \(a > 1\) at the Fe/Cu interfaces of \(M_1\). Nevertheless, from the much higher MR in Fe/Cr multilayers compared to Fe/Cu, one knows that the spin asymmetry at the Fe/Cr interfaces is more pronounced than at the Fe/Cu interfaces [i.e., \(1/a(\text{Fe/Cr}) > a(\text{Fe/Cu})\)], so that the global spin asymmetry coefficient \(a_1\) can be expected to be smaller than 1.

(iii) With \(a_1 < 1\) and \(a_2 > 1\), the additional condition to obtain a reversed MR is to have an AF exchange coupling between \(M_1\) and \(M_2\) across a Cu layer. According to experimental data on Fe/Cu multilayers prepared by sputtering in similar conditions [10], a maximum of AF coupling is obtained for a Cu thickness \(t_{Cu}\) around 14 \(\AA\) (first AF peak). In fact, for a more rigorous test, we have prepared samples with different values of \(t_{Cu}\) between 10 and 20 \(\AA\) in order to check that the inverse MR is maximum around the AF peak, disappears for ferromagnetic coupling \((t_{Cu} = 10 \text{ \(\AA\)})\), and is definitely reduced for weak ferromagnetic coupling \((t_{Cu} = 20 \text{ \(\AA\)})\).

As illustrated in Fig. 3, a reversed MR is observed for thicknesses of Cu providing an antiferromagnetic coupling, with the highest inverse effect for \(t_{Cu} = 16 \text{ \(\AA\)}\), close to the maximum of AF coupling (we will come back later to the correlated variation of the MR and AF coupling). The inverse MR is seen independently of the direction of the field; i.e., the MR curves are very similar for fields parallel and perpendicular to the current in the layer plane. This demonstrates that the MR we observe cannot be due to the so-called anisotropic magnetoresistance (or AMR, resulting from the spontaneous resistivity anisotropy of ferromagnets [5]), and can only be an inverse spin-valve effect. As a matter of fact, the maximum AMR amplitude, measured by rotating the field at saturation, does not exceed 0.2% in our samples, an order of magnitude below the MR effects in Fig. 3.

By looking at the magnetization curve for the sample with \(t_{Cu} = 16 \text{ \(\AA\)}\), in Fig. 3, we first note that the remanent magnetization is only 14% of the magnetization at saturation, which is typical of antiferromagnetic coupling in multilayers. We also note the usual correlation between the field dependences of the resistivity and magnetization. In particular, both the reversed magnetoresistance and magnetization are saturated at about the same relatively low field, around 150 G. This low field, typical of the relatively weak AF coupling in Fe/Cu [10], is the field

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**FIG. 2.** Structure of the multilayers exhibiting inverse MR. One period is represented in the figure. Two iron layers of 12 \(\AA\) coupled ferromagnetically through a thin Cr layer (4 \(\AA\)) compose the magnetic layer \(M_1\). The magnetic layer \(M_2\) is a Fe layer of 15 \(\AA\) and is separated from \(M_1\) by a layer of Cu. The final structure is \((M_1/Cu/M_2/Cu) \times 5\).

**FIG. 3.** Low field MR curves for several \((\text{Fe12 \(\AA\)/Cr4 \(\AA\)/Fe12 \(\AA\)/Cu}) \times 5\) samples are represented in the upper figure. The thickness of Cu, \(t_{Cu}\), is indicated on the curves. For clarity, the curves for \(t_{Cu} = 16\) and 20 \(\AA\) are shifted upward. For the sample with \(t_{Cu} = 16 \text{ \(\AA\)}\), the low field magnetization curve is also shown and can be compared to the MR (lower figure).
which aligns the magnetic moments of the FeCrFe and Fe layers on both sides of Cu.

By looking more carefully at the magnetization data in Fig. 3, we also notice that the saturation at about 150 G is far from being complete; above 150 G, the magnetization continues to increase very slowly and almost linearly. Proceeding to Fig. 4 which represents the magnetization loop in a much larger field range, we see that the magnetization continues to increase slowly and is saturated only at a much higher field around $10^4$ G. This slow increase at high field that we observe in the FeCrFe/Cu/Fe/Cu samples as well as in simple FeCrFe layers can be ascribed to an imperfect ferromagnetic coupling across Cr.

If, for example, we imagine some mixing of AF and F coupling inducing a tilt of $59^\circ$ between the magnetic moments on both sides of Cr, a straightforward calculation shows that an average tilt of $59^\circ$ corresponds to the intermediate saturation step at about 70% (this value of $M/M_s$ is derived by a linear extrapolation to zero field in Fig. 4). We thus have a saturation in two stages: A small field of about 150 G is sufficient to align the magnetic moments of the FeCrFe and Fe layers, and a field exceeding $10^4$ G is necessary to obtain a perfect ferromagnetic alignment within the FeCrFe layers.

The improvement of the ferromagnetic alignment of the Fe half layers on both sides of Cr in the FeCrFe layers is normally expected to induce a normal spin-valve MR at high field, in addition to the reversed MR associated to the relative orientation of the magnetic moments of the Fe and FeCrFe layers on both sides of Cu. This is what we observe when the MR is recorded in a very large field range; see Fig. 4. As shown in the inset of Fig. 4, a similar high field behavior is also found in simple Fe/Cr 6 Å multilayers. For FeCrFe/Cu/Fe/Cu samples, the low field inverse MR adds to the high field normal MR only present in Fe/Cr. We must admit that this mixing of low field inverse and high field normal MR makes the inverse MR effect less clear than might have been expected. However, we emphasize that the inverse and normal MR are observed in clearly different field ranges: The inverse MR is clearly related to the relative orientation of the magnetic moments of the Fe and FeCrFe layers, while the normal MR appears in the high field range characteristic of the coupling across 4 Å of Cr. In addition, to reinforce our interpretation, we have performed several experimental tests that we describe below.

First, as we pointed out above, a reversed MR is expected for $a_1 < 1$ and $a_2 > 1$ (or vice versa) and should disappear for $a_1 = a_2$, i.e., $M_1 = M_2$. For $M_1 = M_2 = Fe$, that is, for Fe/Cu, one already knows that the spin-valve MR is normal (nonreversed) [10]. We also looked at the case $M_1 = M_2 = Fe$ with samples of the type Fe 12 Å Cr 4 Å Fe 12 Å/Cu 14 Å/Fe 12 Å Cr 4 Å Fe 12 Å/Cu 14 Å; they present a normal (nonreversed) spin-valve MR at low field.

![Fig. 4](image)

**FIG. 4.** High field MR and magnetization curves for ([Fe 12 Å/Cr 4 Å/Fe 12 Å/Cu 16 Å/Fe 15 Å/Cu 16 Å] × 5. Inset: MR curve for (Fe 12 Å/Cr 6 Å) × 10.

![Fig. 5](image)

**FIG. 5.** Thickness dependence of the MR ratio for the normal magnetoresistance of Fe/Cu multilayers (4.2 K, Ref. [10]), upper part of the figure) and the inverse MR of the multilayered structures described in this paper (lower part of the figure). The MR ratio of the normal MR is defined as $\rho(\text{field maximum})/\rho(\text{high field})$. The MR ratio of the inverse MR is defined as $\rho(\text{field minimum})/\rho(\text{low field minimum})$ and, with this definition, is negative. The dashed lines are only guides for the eye.
Second, we have to check that our inverse MR cannot be due to a second type of mechanism which, applied to our FeCrFe/Cu/Fe/Cu system, can be described in the following way. Suppose some tilt between the magnetic moments of the two parts of the FeCrFe layer. At zero field, a F coupling across Cu will align the magnetizations on both sides of Cu; but a moderate applied field will align the total magnetic moment of the FeCrFe layer with that of the Fe layer, thus disaligning the magnetizations on both sides of Cu and inducing a reversed MR effect. This second type of mechanism, already seen in some systems at IBM Almaden [12], necessarily implies a ferromagnetic coupling across Cu. We have already seen that the maximum of reversed MR for 16 Å of Cu and the corresponding very small remanent magnetization are consistent with AF coupling. More precisely, we can see in Fig. 5 the correlation between the thickness dependence of the normal MR in Fe/Cu and the reversed MR in FeCrFe/Cu/Fe/Cu. Not only the inverse MR is maximum where the normal MR in Fe/Cu is maximum (maximum AF coupling), but also the inverse MR disappears at t_cu = 9 Å (ferromagnetic coupling and zero MR in Fe/Cu) and is definitely reduced at t_cu = 20 Å (weak F coupling and small MR in Fe/Cu). This convincingly shows that the inverse MR of our samples is associated to AF coupling across Cu and rules out the second mechanism.

We have therefore found an inverse MR of the spin-valve type in Fe/Cu multilayers doped with thin Cr layers and we have shown that this change of sign can be due only to the existence of different spin asymmetry coefficients in neighbor magnetic layers, a_1 < 1 for the FeCrFe layers and a_2 > 1 for the Fe layers. The amplitude of the reversed MR is relatively small around 1% for t_cu = 16 Å, whereas a calculation in the Camley-Barnas free electron model [3] with parameters derived for Fe/Cu and FeCrFe/Cu multilayers predicts a few percent [13]. However, this is not completely surprising, since recent nonfree electron models have shown that channeling effects by the periodic potential of the multilayers can considerably change the magnitude of the MR predicted by free electron models [14,15]. The observation of inverse MR is mainly interesting as a fundamental test for the basic idea of the standard interpretation of the GMR (illustrated by Fig. 1). A failure of this test would have questioned the basis of almost all the existing models. Changing the sign of the MR by introducing thin Cr layers is also a good example of the potential of spin engineering for modeling the properties of multilayers.

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[13] The parameters of a Camley-Barnas model [3] for our multilayers are, for each spin direction, the transmission coefficient of the Fe/Cr interfaces (involved in layer M_1 only), the transmission coefficient of the Fe/Cu interfaces, the mean free path in Fe (involved in both M_1 and M_2 layers), and, finally, the mean free path in Cu. We have determined the parameters of the Fe/Cu interfaces and Fe and Cu layers also by fitting experimental data on M_j/Cu (i.e., Fe/Cu) multilayers. The transmission coefficient at the Fe/Cr interfaces is found from experimental data on M_j/Cu multilayers. Then all these parameters are combined to calculate the MR of (M_j/Cu/M_j/Cu). This calculation and tables of parameters will be presented in a longer article. As indicated in the text, this calculation leads to inverse MR of a few percent (instead of 1% or less). Channeling effects (as those described in Refs. [14,15] and not taken into account in the Camley-Barnas model) can account for this discrepancy. Also, owing to the competition between the Fe/Cr and Fe/Cu interfaces in layers M_1, the final result is very sensitive to any uncertainty on the parameters.
FIG. 2. Structure of the multilayers exhibiting inverse MR. One period is represented in the figure. Two iron layers of 12 Å coupled ferromagnetically through a thin Cr layer (4 Å) compose the magnetic layer \( M_1 \). The magnetic layer \( M_2 \) is a Fe layer of 15 Å and is separated from \( M_1 \) by a layer of Cu. The final structure is \((M_1/Cu/M_2/Cu) \times 5\).